

HIGH POWER LINEAR AMPLIFIER

Typical Applications

- 2.5 GHz ISM Band Applications
- Digital Communication Systems
- PCS Communication Systems
- Commercial and Consumer Systems
- Portable Battery-Powered Equipment

Product Description

The RF2126 is a high-power, high-efficiency, linear amplifier IC. The device is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (HBT) process and has been designed for use as the final RF amplifier in 2.45 GHz ISM applications such as WLAN and POS terminals. The part will also function as the final stage in digital PCS phone transmitters requiring linear amplification operating between 1800MHz 2500 MHz. The device is packaged in an 8-lead plastic package with a backside ground. The device is self-contained with the exception of the output matching network and power supply feed line. It produces a typical output power level of 1W.

3.90 Exposed 0.05 П 2.70 \neg 6.00 ± 0.20 ± 0.10 1.70 ± 0.10 Dimensions in mm. 8° MAX 0° MIN ± 0.03 NOTES: 1. Shaded lead is pin 1 0.60 2. Lead coplanarity - 0.10 with respect to datum "A". + 0.15

Package Style: SOIC-8 Slug

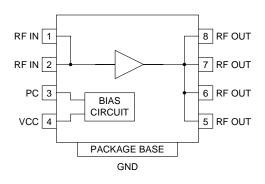
Optimum Technology Matching® Applied Si BJT

Si Bi-CMOS

▼ GaAs HBT

GaAs MESFET

☐ SiGe HBT ☐ Si CMOS



Functional Block Diagram

Features

- Single 3V to 6.5V Supply
- 1.3W Output Power
- 12dB Gain
- 45% Efficiency
- Power Down Mode
- 1800MHz to 2500MHz Operation

Ordering Information

RF2126 High Power Linear Amplifier RF2126 PCBA Fully Assembled Evaluation Board

RF Micro Devices, Inc. Tel (336) 664 1233 7625 Thorndike Road Fax (336) 664 0454 Greensboro, NC 27409, USA http://www.rfmd.com

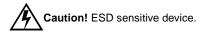
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RF2126

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V _{CC})	-0.5 to +7.5	V_{DC}
Power Control Voltage (V _{PC})	-0.5 to +5 V	V
DC Supply Current	450	mA
Input RF Power	+20	dBm
Output Load VSWR	20:1	
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +100	°C

Refer to "Handling of PSOP and PSSOP Products" on page 16-15 for special handling information.



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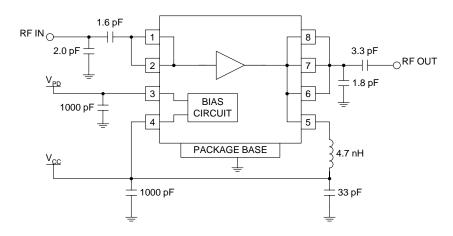
Parameter	Specification		Unit	Condition		
Parameter	Parameter Min. Typ. Max.		Onit			
Overall					T=25 °C, V_{CC} =6.0 V, V_{PC} =3.0 V, Z_{LOAD} =12 Ω , P_{in} = 0 dBm, Freq=2450 MHz, Idle current=180 mA	
Frequency Range	1800		2500	MHz		
Maximum Output Power		+27.0		dBm	V_{CC} =3.6V, P_{IN} =+19dBm	
Maximum Output Power		+29		dBm	V_{CC} =4.8V, P_{IN} =+19dBm	
Maximum Output Power	+30.0	+31.0		dBm	V _{CC} =6.0V, P _{IN} =+19dBm	
Total Power Added Efficiency		45		%	Maximum output, V _{CC} =3.6V	
Total Power Added Efficiency		45		%	Maximum output, V _{CC} =4.8V	
Total Power Added Efficiency		45		%	Maximum output, V _{CC} =6.0V	
Small-signal Gain		12		dB		
Second Harmonic		-55		dBc	See Application Schematic, P _{IN} =+17dBm	
Third Harmonic		-60		dBc		
Input VSWR		1.5:1			With external matching network; see application schematic	
Two-tone Specification						
Average Two-Tone Power		+27		dBm	PEP-3dB	
IM ₃	-24	-25		dBc	P _{OUT} =+24dBm for each tone	
IM ₅		-35		dBc	P _{OUT} =+24dBm for each tone	
IM ₇		-55		dBc	P _{OUT} =+24dBm for each tone	
Power Control						
V _{PC}	1.5	3.0	3.5	V	To obtain 180 mA idle current	
Power Control "OFF"	0.2	0.5		V	Threshold voltage at device input	
Power Supply						
Power Supply Voltage	3.0		6.5	V		
Supply Current	270	350	410	mA	P_{OUT} =+30dBm, V_{CC} =6.0V	
Power Down Current		0.5	10	μΑ	V _{PC} =0.2V	

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Pin	Function	Description	Interface Schematic
1	RF IN	RF input. This input is DC coupled, so an external blocking capacitor is required if this pin is connected to a DC path. An optimum match to 50Ω is obtained by providing an external series capacitor of 1.6pF and then a shunt capacitor of 2.0pF; see the Application Schematic. Those values are typical for 2450MHz; other values may be required for other frequencies.	
2	RF IN	Same as pin 1.	
3	PC	Power control pin. For obtaining maximum performance the voltage on this pin can be used to set correct bias level. In a typical application this is implemented by a feedback loop. The feedback can be based on the actual supply current of the device, i.e. maintaining a fixed current level, or it can be based on the RF output power level to maintain a fixed RF power level (Automatic Level Control loop). A voltage of 0.5 V or lower brings the part into power down state.	
4	VCC	Power supply pin for the bias circuits. External low frequency bypass capacitors should be connected if no other low frequency decoupling is nearby.	
5	RF OUT	RF output and bias for the output stage. The power supply for the output transistor needs to be supplied to this pin. This can be done through a quarter-wavelength microstrip line that is RF grounded at the other end, or through an RF inductor that supports the required DC currents. Optimum load impedance is achieved by providing a shunt capacitor of 1.8pF and a series capacitor of 3.3pF; see the Application Schematic. Those values are typical for 2450MHz; other values may be required for other frequencies. Since there are several output pins available, which are internally connected, one pin can be used for connecting the bias, another for connecting a (third) harmonic trap filter, and the other pins for the RF output.	
6	RF OUT	Same as pin 5.	
7	RF OUT	Same as pin 5.	
8	RF OUT	Same as pin 5.	
Pkg Base	GND	Ground connection. The backside of the package should be connected to the ground plane through a short path, i.e., vias under the device may be required.	

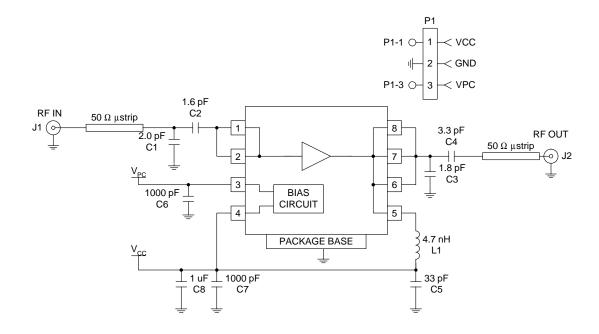
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Application Schematic 2450MHz Operation



Evaluation Board Schematic 2450 MHz Operation

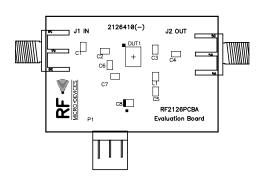
(Download Bill of Materials from www.rfmd.com.)

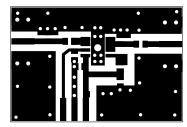


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Evaluation Board Layout 1.5" x 1.0"

Board Thickness 0.031", Board Material FR-4





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